VS-25F(R) Series

Vishay Semiconductors



Standard Recovery Diodes (Stud Version), 25 A



PRODUCT SUMMARY			
I _{F(AV)}	25 A		
Package	DO-203AA (DO-4)		
Circuit configuration	Single diode		

FEATURES

- High surge current capability
- Stud cathode and stud anode version
- Wide current range
- Types up to 1200 V V_{RRM}
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Battery charges
- Converters
- Power supplies
- Machine tool controls

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		25	А	
I _{F(AV)}	T _C	120	°C	
I _{F(RMS)}		40	А	
I _{FSM}	50 Hz	356	٥	
	60 Hz	373	A	
10	50 Hz	636	A ² s	
l ² t	60 Hz	580	A-S	
V _{RRM}	Range	100 to 1200	V	
TJ		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I _{RRM} MAXIMUM AT TJ = 175 °C mA	
	10	100	150		
	20	200	275		
	40	400	500		
VS-25F(R)	60	600	725	12	
	80	800	950		
	100	1000	1200		
	120	1200	1400		

Revision: 16-Nov-15 1 Document Number: 93506 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	180° conduction, half sine wave		25	A	
at case temperature	'F(AV)			navo	120	°C
Maximum RMS forward current	I _{F(RMS)}				40	A
		t = 10 ms	No voltage		356	A
Maximum peak, one-cycle forward,	1	t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = T _J maximum	373	
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM}		300	
		t = 8.3 ms	reapplied		314	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage reapplied		636	A ² s
		t = 8.3 ms			580	
		t = 10 ms	100 % V _{RRM} reapplied		450	
		t = 8.3 ms			410	
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		6360	A²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), T _J = T _J maximum		0.80	v	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$		0.90	v	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum		6.80	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$		5.70	11152	
Maximum forward voltage drop	V _{FM}	$I_{pk} = 78 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu\text{s} \text{ rectangular wave}$		1.30	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	TJ		-65 to +175	°C
Maximum storage temperature range	T _{Stg}		-65 to +200	0
Maximum thermal resistance, junction to case	R _{thJC}			K/W
Maximum thermal resistance, case to heat sink	R _{thCS}			
		Not lubricated threads	1.5 + 0 - 10 % (13)	N · m (lbf · in)
Allowable mounting torque		Lubricated threads	1.2 + 0 - 10 % (10)	N · m (lbf · in)
Approximate weight			7	g
			0.25	oz.
Case style		See dimensions - link at the end of datasheet	DO-203AA	A (DO-4)

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.28	0.24			
120°	0.39	0.41			
90°	0.50	0.54	$T_J = T_J maximum$	K/W	
60°	0.73	0.75			
30°	1.20	1.21			

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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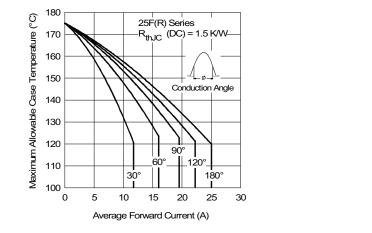


Fig. 1 - Current Ratings Characteristics

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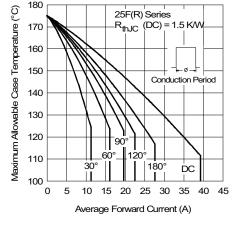


Fig. 2 - Current Ratings Characteristics

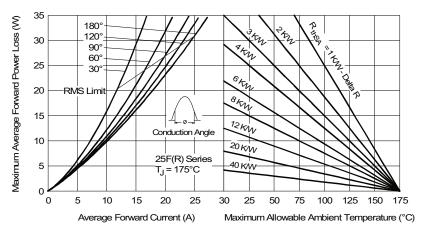
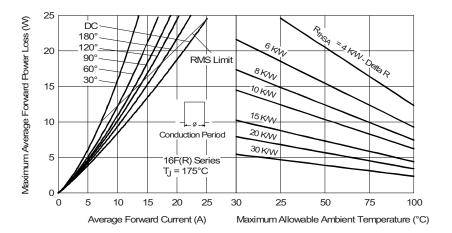
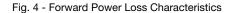


Fig. 3 - Forward Power Loss Characteristics







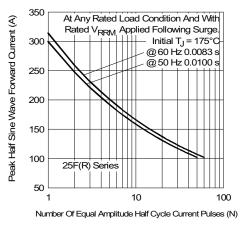


Fig. 5 - Maximum Non-Repetitive Surge Current

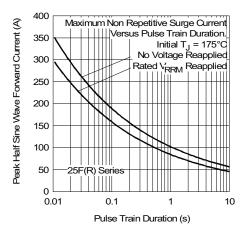


Fig. 6 - Maximum Non-Repetitive Surge Current

ORDERING INFORMATION TABLE



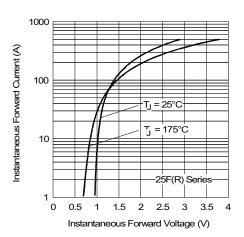


Fig. 7 - Forward Voltage Drop Characteristics

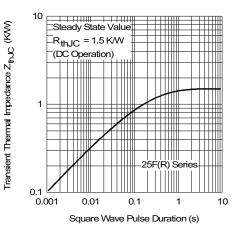
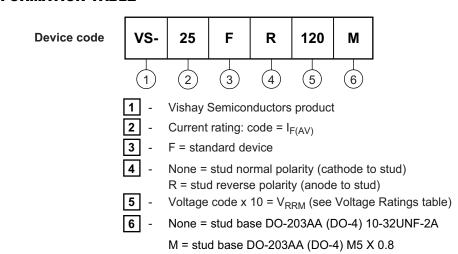


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95311				
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R 0.40 R (0.02)

Ø 6.8 (0.27)

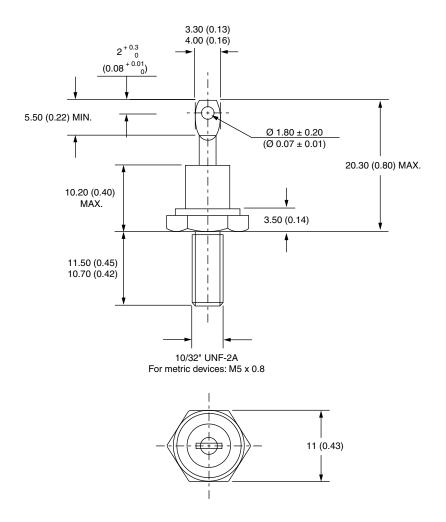
 0.8 ± 0.1

 (0.03 ± 0.004)



DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)







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